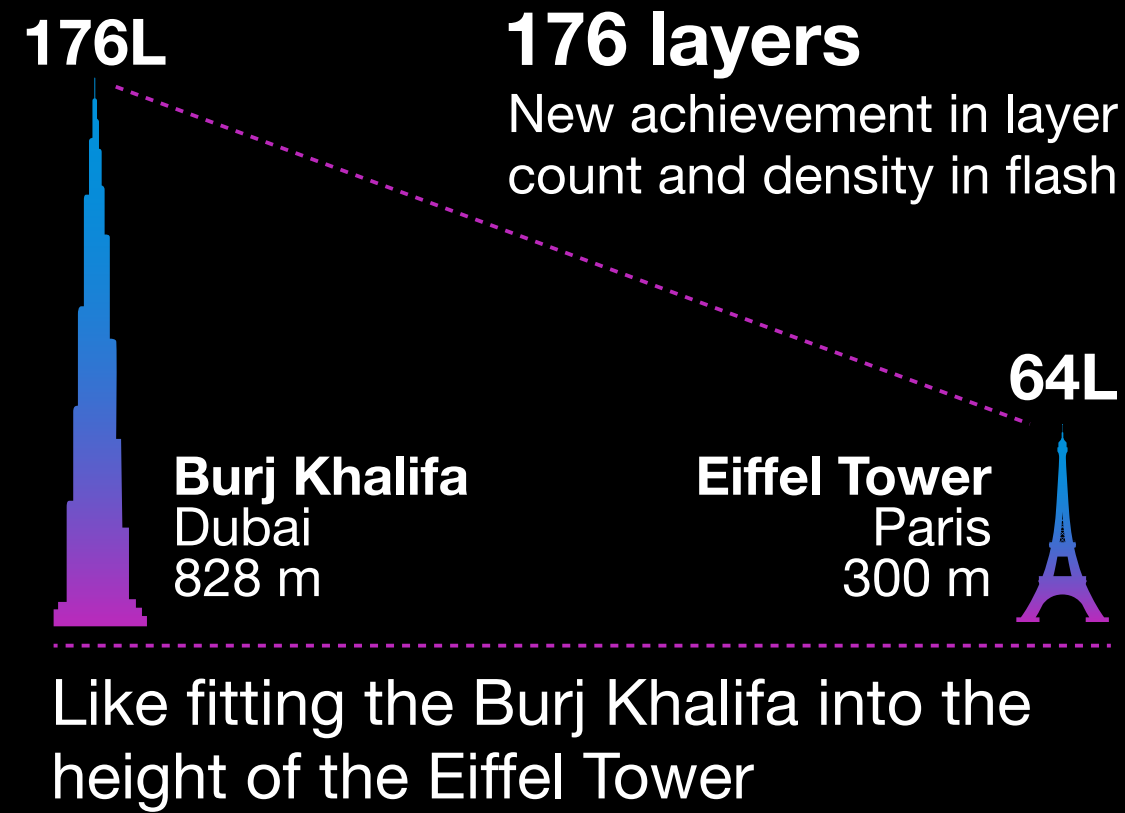


Micron's Leap Forward in NAND

Broad impact from drones to data centers

176-layer NAND from Micron enables a wide variety of low-power, high-speed, dense storage solutions across a broad range of applications:

- Drones
- Phones
- Consoles
- Surveillance
- Artificial Intelligence
- Laptops
- Automobiles
- Data Centers



Remarkably small
Each 176-layer die is 1/5 the thickness of a sheet of paper

Benefits of Micron's 176-layer replacement gate architecture*

30%
smaller die size**

35%
improved read and write latency

33%
increase in transfer rate to 1,600 MT/s (ONFi bus)

*Comparison is based on Micron's high-volume, floating-gate 96-layer NAND

**Approximately vs. industry best-in-class